

International
IOR Rectifier

MBRB7..PbF

SCHOTTKY RECTIFIER

7.5 Amp

$$I_{F(AV)} = 7.5\text{Amp}$$

$$V_R = 35 - 45\text{V}$$

Major Ratings and Characteristics

Characteristics	Values	Units
$I_{F(AV)}$ Rectangular waveform	7.5	A
V_{RRM}	35 - 45	V
I_{FSM} @ $t_p = 5\mu\text{s}$ sine	690	A
V_F @ 7.5Apk, $T_J = 125^\circ\text{C}$	0.57	V
T_J range	- 65 to 150	$^\circ\text{C}$

Description/ Features

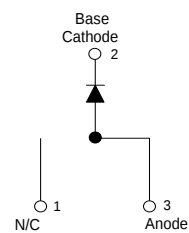
The MBRB7.. Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150°C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- 150°C T_J operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead-Free ("PbF" suffix)

Case Styles



D²PAK



Voltage Ratings

Parameters	MBRB735PbF	MBRB745PbF
V_R Max. DC Reverse Voltage (V)	35	45
V_{RWM} Max. Working Peak Reverse Voltage (V)		

Absolute Maximum Ratings

Parameters	MBR..	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	7.5	A	@ $T_C = 131^\circ\text{C}$ (Rated V_R)
I_{FSM} Non-Repetitive Peak Surge Current	690	A	5 μs Sine or 3 μs Rect. pulse Following any rated load condition and with rated V_{RRM} applied
	150		Surge applied at rated load condition halfwave single phase 60Hz
E_{AS} Non-Repetitive Avalanche Energy	7	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 2\text{ Amps}$, $L = 3.5\text{ mH}$
I_{AR} Repetitive Avalanche Current	2	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical

Electrical Specifications

Parameters	MBR..	Units	Conditions
V_{FM} Max. Forward Voltage Drop (1)	0.84	V	@ 15A $T_J = 25^\circ\text{C}$
	0.57	V	@ 7.5A $T_J = 125^\circ\text{C}$
	0.72	V	@ 15A
I_{RM} Max. Instantaneous Reverse Current (1)	0.1	mA	$T_J = 25^\circ\text{C}$ Rated DC voltage
	15	mA	$T_J = 125^\circ\text{C}$
C_T Max. Junction Capacitance	400	pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) 25°C
L_S Typical Series Inductance	8.0	nH	Measured from top of terminal to mounting plane
dv/dt Max. Voltage Rate of Change (Rated V_R)	10000	V/ μs	

(1) Pulse Width < 300 μs , Duty Cycle <2%

Thermal-Mechanical Specifications

Parameters	MBR..	Units	Conditions
T_J Max. Junction Temperature Range	-65 to 150	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-65 to 175	$^\circ\text{C}$	
R_{thJC} Max. Thermal Resistance Junction to Case	3.0	$^\circ\text{C/W}$	DC operation
R_{thCS} Typical Thermal Resistance, Case to Heatsink	0.50	$^\circ\text{C/W}$	Mounting surface, smooth and greased
wt Approximate Weight	2 (0.07)	g (oz.)	
T Mounting Torque	Min. 6 (5)	Kg-cm (lbf-in)	
	Max. 12 (10)		
Marking Device	MBRB7..		Case style D ² Pak

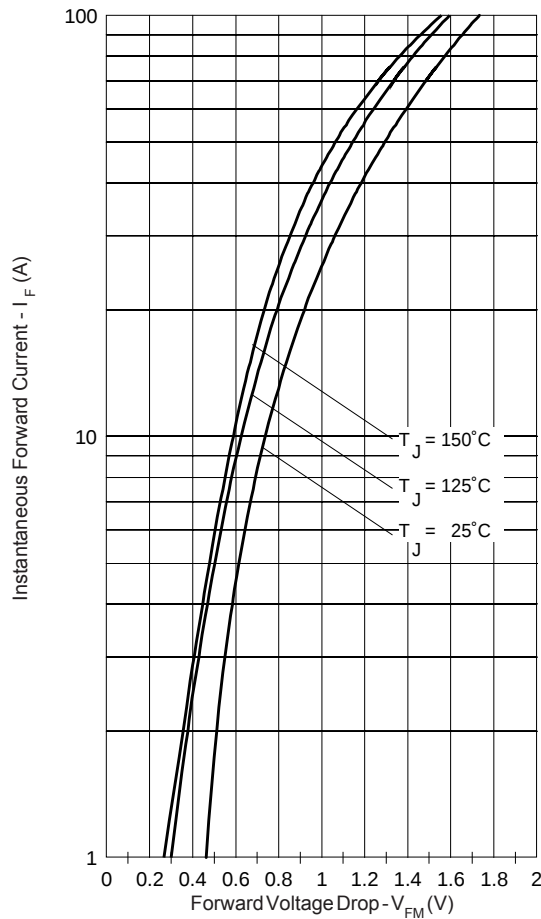


Fig. 1 - Max. Forward Voltage Drop Characteristics (Per Leg)

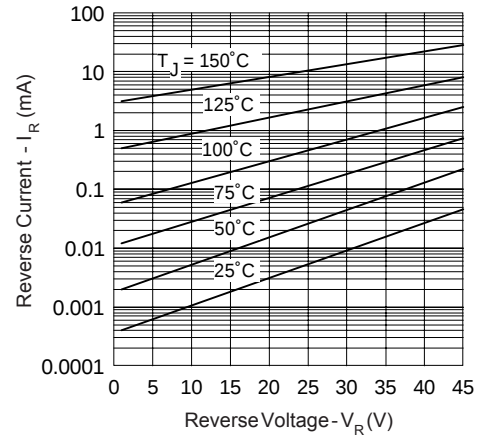


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage (Per Leg)

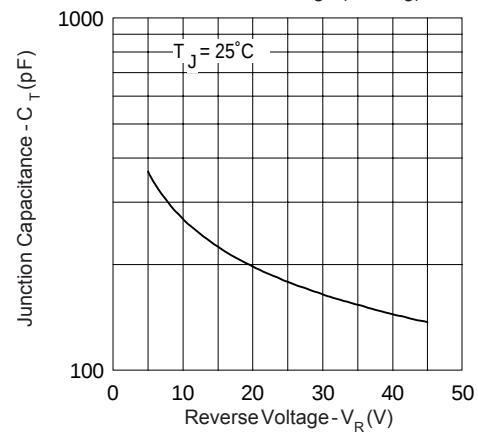


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage (Per Leg)

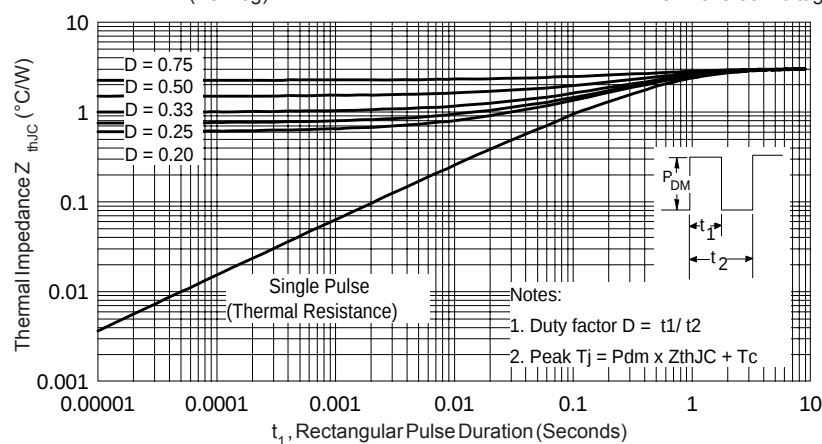


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics (Per Leg)

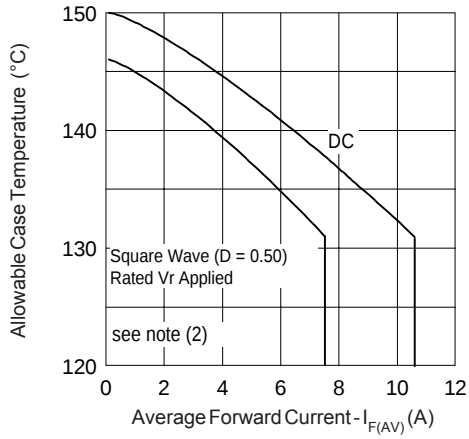


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

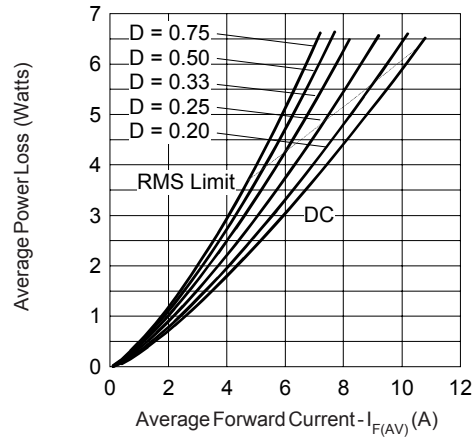


Fig. 6 - Forward Power Loss Characteristics

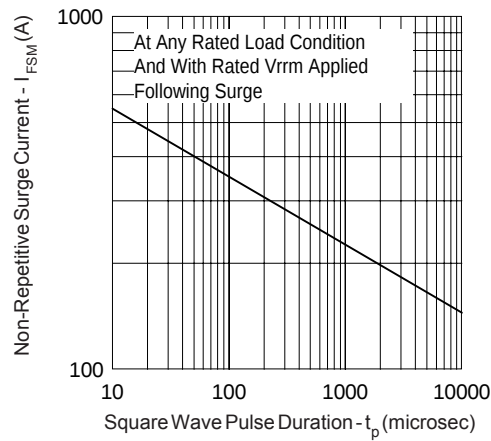


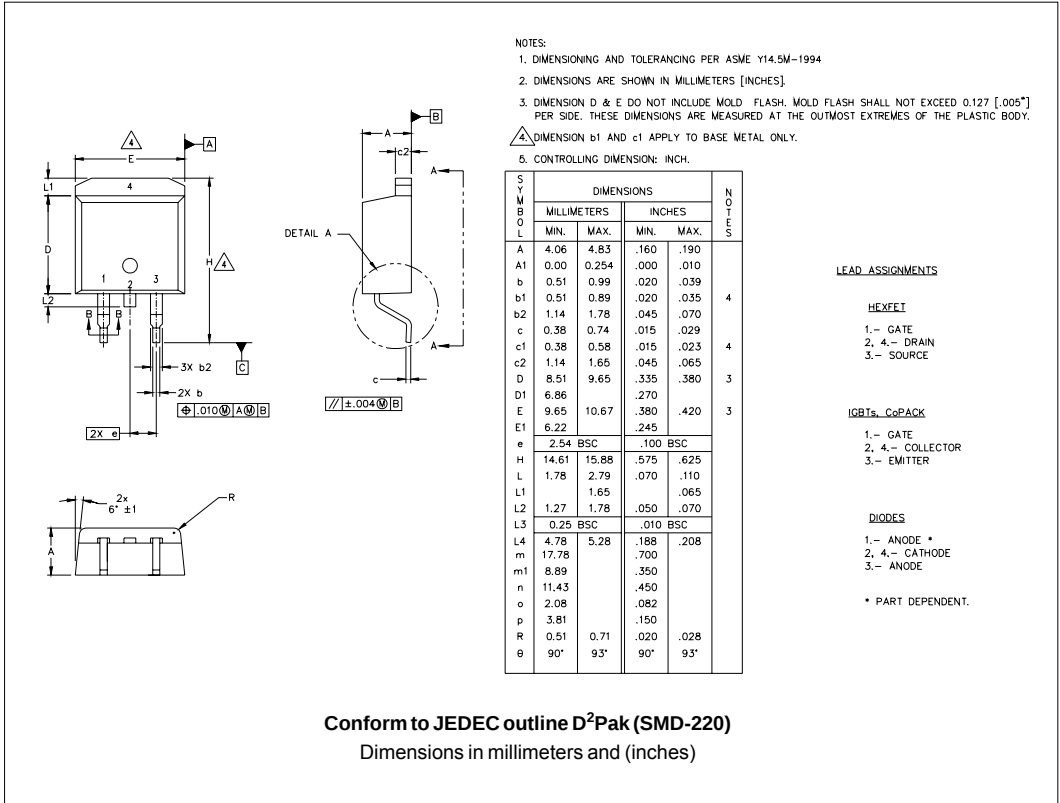
Fig. 7 - Max. Non-Repetitive Surge Current (Per Leg)

(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

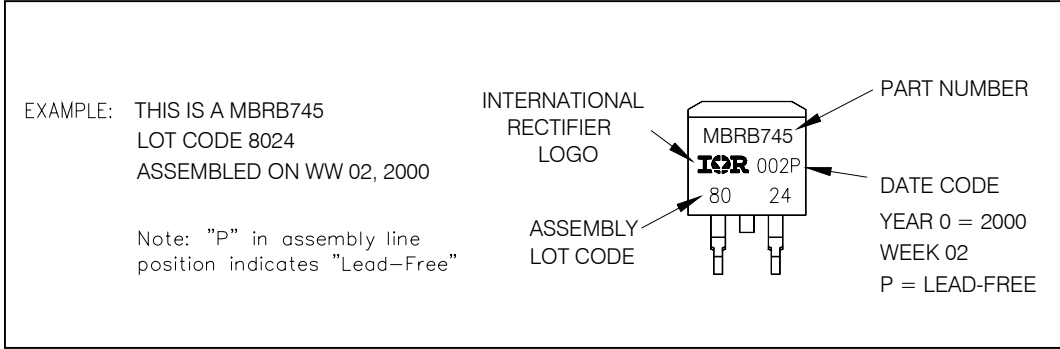
Pd = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

Pd_{REV} = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1}$ = rated V_R

Outline Table



Part Marking Information



The technical drawing illustrates the dimensions of a carrier assembly. It includes a side view labeled "SECTION Y-Y" and a top view. The side view shows a cross-section with dimensions: 0.35±0.05, 0.12 max, R, B2, K_o, and 1.20. The top view shows a rectangular carrier with four sprocket holes. Key dimensions include P₂ = 2.0±0.1, P_o = 4.0±0.1, F = 1.75±0.1, W, A_o, P₁, R 0.3 Typical, ø1.6 ±0.1, ø1.55±0.05, 2.17±0.1, 1.57±0.1, and B_o. Notes specify tolerances and measurement methods.

SECTION Y-Y

A _o	10.50	+/-	0.1
B _o	15.80	+/-	0.1
B2	10.25	+/-	0.1
K _o	4.90	+/-	0.1
F	11.50	+/-	0.1
P ₁	16.00	+/-	0.1
W	24.00	+/-	0.3

NOTES:

- 1.0 10 SPROCKET HOLE PITH CUMULATIVE TOLERANCE ±0.2
- 2.0 CAMBER NOT TO EXCEED 1mm IN 100mm
- 3.0 MATERIAL: CONDUCTIVE BLACK STYRENIC ALLOY
- 4.0 K_o MEASURED FROM A PLANE ON THE INSIDE BOTTOM OF THE POCKET TO THE TOP SURFACE OF THE CARRIER
- 5.0 MEASURED FROM CENTRELNE OF SPROCKET HOLE TO CENTRELNE OF POCKET
- 6.0 VENDOR: (OPTIONAL)
- 7.0 MUST ALSO MEET REQUIREMENTS OF EIA STANDAR #EIA-481A TAPING OF SURFACE MOUNT COMPONENTS FOR AUTOMATIC PLACEMENT
- 8.0 SURFACE RESISTIVITY OF MOLDED MATL. MUST MEASURE LESS OR EQUAL TO 10⁶ OHMS PER SQUARE. MEASURED IN ACCORDANCE TO PROCEDURE GIVEN IN ASTM D-257 & ASTM D-991
- 9.0 TOTAL LENGTH PER REEL MUST BE 45 METERS
- 10.0 Ⓢ CRITICAL

Dimensions in millimeters and (inches)

Device Code

MBR	B	7	45	TRL	PbF
1	2	3	4	5	6

1 - Essential Part Number
2 - B = Surface Mount
 None = TO-220
3 - Current Rating (7.5A)
4 - Voltage code: Code = V_{RRM} 35 = 35V
45 = 45V
5 - • none = Tube (50 pieces)
 • TRL = Tape & Reel (Left Oriented - for D²Pak only)
 • TRR = Tape & Reel (Right Oriented - for D²Pak only)
6 - • none = Standard Production
 • PbF = Lead-Free

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MBR745
*****
*   This model has been developed by   *
*   Wizard SPICE MODEL GENERATOR (1999) *
*   (International Rectifier Corporation) *
*   contains Proprietary Information   *
*****
* SPICE Model Diode is composed by a   *
* simple diode plus paralalled VCG2T   *
*****

.SUBCKT MBR745 ANO CAT
D1 ANO 1 DMOD (0.03191)
*Define diode model
.MODEL DMOD D(IS=9.72464638473799E-05A,N=1.30648926537753,BV=52V,
+IBV=0.195508065728349A,RS=0.000727548,CJO=1.94829876431799E-08,
+VJ=2.27282978121533,XTI=2, EG=0.854458710837653)
*****
*Implementation of VCG2T
VX 1 2 DC 0V
R1 2 CAT TRES 1E-6
.MODEL TRES RES(R=1,TC1=27.6281424524011)
GP1 ANO CAT VALUE={-ABS(I(VX))*(EXP(((((-5.219758E-03/27.62814)*((V(2,CAT)*1E6)/(I(VX)+1E-6)-
1))+1)*7.000165E-02*ABS(V(ANO,CAT))))-1}}
*****
.ENDS MBR745

Thermal Model Subcircuit
.SUBCKT MBR745 5 1

CTHERM1      5      4      1.05E+00
CTHERM2      4      3      4.44E+00
CTHERM3      3      2      1.16E+01
CTHERM4      2      1      6.12E+01

R THERM1      5      4      1.33E+00
R THERM2      4      3      1.19E+00
R THERM1      3      2      3.81E-01
R THERM1      2      1      9.54E-02

.ENDS MBR745

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Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level and Lead-Free.
Qualification Standards can be found on IR's Web site.

International
IR Rectifier

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